



PATENT

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Applicant: Jerome M. Eldridge et al. Examiner: Tu-Tu Ho  
Serial No.: 10/081,818 Group Art Unit: 2818  
Filed: February 20, 2002 Docket: 1303.045US1  
Title: ATOMIC LAYER DEPOSITION OF METAL OXIDE AND/OR LOW ASYMMETRICAL TUNNEL BARRIER INTERPOLY INSULATOR

**COMMUNICATION CONCERNING RELATED APPLICATION(S)**

Mail Stop Amendment  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Applicants would like to bring to the Examiner's attention the following related application(s) in the above-identified patent application:

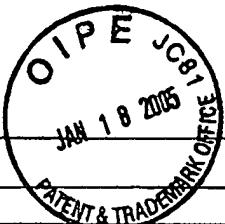
<u>Serial/Patent No.</u>	<u>Filing Date</u>	<u>Attorney Docket</u>	<u>Title</u>
10/929916	August 30, 2004	1303.035US2	PROGRAMMABLE ARRAY LOGIC OR MEMORY WITH P-CHANNEL DEVICES AND ASYMMETRICAL TUNNEL BARRIERS
10/931704	September 1, 2004	1303.014US2	FLASH MEMORY WITH LOW TUNNEL BARRIER INTERPOLY INSULATOR
10/929986	August 30, 2004	1303.045US2	ATOMIC LAYER DEPOSITION OF METAL OXIDE AND/OR LOW ASYMMETRICAL TUNNEL BARRIER INTERPOLY INSULATOR
10/931711	September 1, 2004	1303.029US2	PROGRAMMABLE MEMORY ADDRESS AND DECODE CIRCUITS WITH LOW TUNNEL BARRIER INTERPOLY INSULATOR
10/931540	August 31, 2004	1303.020US2	PROGRAMMABLE ARRAY LOGIC OR MEMORY DEVICES WITH ASYMMETRICAL TUNNEL BARRIERS

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Substitute for form 1449A/PTO

**INFORMATION DISCLOSURE  
STATEMENT BY APPLICANT**

(Use as many sheets as necessary)



Sheet 1 of 1

Complete if Known

<b>Application Number</b>	10/081,818
<b>Filing Date</b>	February 20, 2002
<b>First Named Inventor</b>	Eldridge, Jerome
<b>Group Art Unit</b>	2818
<b>Examiner Name</b>	Ho, Tu-Tu

Attorney Docket No: 1303.045US1

**US PATENT DOCUMENTS**

Examiner Initials*	USP Document Number	Publication Date	Name of Patentee or Applicant of cited Document	Filing Date If Appropriate
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**FOREIGN PATENT DOCUMENTS**

Examiner Initials*	Foreign Document No	Publication Date	Name of Patentee or Applicant of cited Document	T <sup>2</sup>

**OTHER DOCUMENTS -- NON PATENT LITERATURE DOCUMENTS**

Examiner Initials*	Cite No <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T <sup>2</sup>

EXAMINER Tu-Tu + HO

DATE CONSIDERED Feb. 2005

Substitute Disclosure Statement Form (PTO-1449)

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